# IGD1205W

# Hybrid Integrated Isolated N-Channel IGBT Driver

# **Electrical Specifications**

# **Key Features:**

- Internal DC/DC Converter
- Internal OptoCoupler
- 30 kV/µS CMR
- VISO = 3,750V
- TTL Compatible Input
- Short Circuit Protected
- Fault Signal Output
- Switching Freq. to 20 kHz
- Compact SIP Package

## **Recommended For:**

- 600V Series IGBT (up to 600A)
- 1200V Series IGBT (up to 400A)
- 1700V Series IGBT (up to 200A)





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| Parameter             |       | Conditions M                                  |     | Тур. | Max.  | Units |
|-----------------------|-------|---|-----|------|-------|-------|
| Supply Voltage        | VD    | IGD1205W-12                                   |     |      | 13    |       |
| Supply voltage        | VD    | D IGD1205W-15                                 |     |      | 16    | VDC   |
| Input Voltage         | Vin   | See Note 3                                    |     |      | 50    | VDC   |
| Input Current         | lin   | See Note 4                                    |     |      | 25    | mA    |
| Output Voltage        | Vo    | When Output is "H"                            |     |      | Vcc   | VDC   |
| Output Current        | IGON  | Dulas Width Que, Fraguenou - 20 kl Iz         |     |      | +5.0  | А     |
| Output Current        | IGOFF | Pulse Width $2\mu$ S, Frequency $\geq 20$ kHz |     |      | -5.0  |       |
| Isolation Voltage     | Viso  | Sine Wave Voltage 50 Hz/ 60 Hz , 1 Min        |     |      | 3,750 | VAC   |
| Operating Temperature | Тор   |   | -40 |      | +70   | °C    |
| Storage Temperature   | Tst   |   | -50 |      | +125  | °C    |
| Fault Output Current  | IFO   | See Note 5                                    |     |      | 20    | mA    |

)del: IGD1205-15

#### Electrical Characteristics, TA = 25 °C, Vcc = 15 VDC, VEE = -10 VDC unless otherwise noted.

Absolute Maximum Ratings,  $T_A = 25 \text{ °C}$ ,  $V_D = 12V$  or 15V,  $R_G = 5\Omega$ , unless otherwise noted.

| Parameter                    |        | Conditions                    | Min. | Тур. | Max.  | Units |  |
|------------------------------|--------|-------------------------------|------|------|-------|-------|--|
| Cupply Voltage               | Vd     | IGD1205W-12 Recommended Range | 11.6 | 12   | 12.4  | VDC   |  |
| Supply voltage               | VD     | IGD1205W-15 Recommended Range | 14.5 | 15   | 15.5  |       |  |
| Switching Frequency          | f      | Recommended Range             | 0    |      | 20    | kHz   |  |
| Gate Resistor                | Rg     |                               | 2    |      |       | Ω     |  |
| Cata Supply Voltage          | Vcc    |                               | 14.5 |      | 18.0  | VDC   |  |
| Gate Supply voltage          | VEE    |                               | -7.0 |      | -10.0 |       |  |
| Input CMR                    |        |                               | 15   | 30   |       | kV/μS |  |
| "H" Input Current            | Ін     | Recommended Range             | 10   | 16   | 20    | mA    |  |
| "H" Output Voltage           | Vон    |                               | 13.5 | 15.3 | 17.0  | VDC   |  |
| "L" Output Voltage           | Vol    |                               | -6   |      | -10   | VDC   |  |
| "L-H" Propagation            | TPLH   | Iн = 16 mA                    |      | 0.5  | 1.0   | μS    |  |
| "L-H" Rise Time              | TR     | Iн = 16 mA                    |      | 0.3  | 1.0   | μS    |  |
| "H-L" Propagation            | TPHL   | Iн = 16 mA                    |      | 1.0  | 1.3   | μS    |  |
| "H-L" Fall Time              | TF     | Iн = 16 mA                    |      | 0.3  | 1.0   | μS    |  |
| Protection Threshold Voltage | VOCP   |                               |      | 9.5  |       |       |  |
| Protection Reset Time        | TTIMER | Between Start & Cancel        | 1.0  | 1.4  | 2.0   | mS    |  |
| Fault Output Current         | Ifo    | See Note 6                    |      | 5.0  |       | mA    |  |
| Controlled Time Detect       | TTRIP1 | Short Circuit 1, See Note 7   |      | 2.6  |       | μS    |  |
| Soft Turn-Off Time           | TCF    | See Note 8                    |      | 4.5  |       | μS    |  |
| SC Detect Voltage            | Vsc    | Collector Voltage of Module   | 15   |      |       | VDC   |  |

Notes:

1. Exceeding Absolute Maximum Ratings may damage the module. These are not continuous operating ratings.

2. "H" = high level signal. "L" = low level signal.

3. The voltage applied to pin 14.

4. The current measured between pins 13 and 14.

5. The input current at pin 15.

6. The input current at pin 15. R<sub>4</sub> = 4.7 kΩ.

7. Pin  $13 \ge 15$  VDC. Pin 16 open. 8. Pin  $13 \ge 15$  VDC. Pin 14 open.

9. Pin 1  $\ge$  15 VDC. Fill 14

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# Typical Connection

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### Connection Notes:

To minimize the potential for problems (and/or failures) caused by induced noise, EMI interference and/or oscillation, the connection of the gate driver must be done with great care. Some recommendations would include:

- 1 The D200E is a 2W DC/DC converter. It will convert a 5. 12. or 24V bus voltage to the 12 or 15V needed to power the IGD1205W. The SR7805 is a switching POL regulator. It provides a stable 5V input signal voltage to the input (pin 14) of the IGD1205W.
- 2 The input signal voltage (pin 14) cannot exceed 5.0V. The internal dissipation caused by the resultant increase in input current could damage the input optocoupler. A current limiting resistor (R1) is used to help prevent this. The resistor value is calculated by the formula:

$$R_1 = \frac{V_{IN} - 1.7V}{16 \,\text{mA}} - 150\Omega$$

- 3 The gate wiring of the IGBT gate-emitter drive loop must be shorter than 1 meter.
- 4 Twisted pair wiring is recommended for the gate-emitter drive loop to 7 minimize mutual induction

#### **Mechanical Dimensions** 2.047 (52.00) M

5 If a large voltage spike is generated at the IGBT collector, the value of 8 The voltage level at pin 4 could go "High" depending on the reverse the gate resistor (Rg) should be increased.

The IGD1205W includes an internal DC/DC converter that provides isolated gate drive power at pin 9 (Vcc, 15V) and pin 7 (VEE, -8V). These outputs share a common ground at pin 8. This allows the IGD to provide a floating gate drive suitable for high or low side switching. Low impedance electrolytic capacitors (C6 and C7) are used to decouple the internal supply outputs. It is important that these components be selected for low impedance and a maximum allowable ripple current that is sufficinet for the application. Assuming the ripple current in the decoupling capacitors is about equal to the rms gate current, it can be estimated by the formula:

$$i_{\rm RMS} = i_{\rm P} \sqrt{\frac{t_{\rm P} \times f}{3}}$$

Where  $i_P$  = peak current;  $t_P$  = base width of pulse; and f = frequency. Capacitors C6 and C7 should be mounted as close to the driver as possible.

The peak reverse voltage rating of D1 must be higher than the peak value of the IGBT collector voltage.

- recovery characteristics of D1. A 30V zener diode DZ1 is connected between pin 4 and pin 7 to prevent any problems caused by this.
- If the short cicuit protection circuit is not used, a 4.7 k $\Omega$ should be connected between pin 4 and pin 8.
- 10 The IGD1205W has a short circuit detection time delay of 1.6  $\mu$ S. Sufficient for most applications. If required, this can be extended by connecting a capacitor (CTRIP) between pin 1 and pin 9. Contact the factory for details. If used, CTRIP should be mounted as close to the driver as possible.
- 11 To help limit any transient voltage surges that could occur when a shor circuit is interrupted, a soft shutdown is provided by the IGD1205W. The default time is set to 4.5  $\mu$ S, but it can be adjusted from 2.5  $\mu$ S to 10  $\mu$ S by using either CF or RF. Contact the factory for details.
- 12 If the IGD1205W short circuit protection is activated, it will immediately shut down the gate drive and pull pin 2 low to indicate a fault (via OP1). During normal operation, the collector of OP1 is pulled high by R2. In the event of a fault, the driver output is disabled and a fault signal is produced that lasts a minimum of 1 mS. The RC filter (C5 and R3) help provide noise immunity. If the short circuit protection circuit is not used, these components can be eliminated and pin 2 should be left open.

## **Model Selection Guide**

| Model Number | Input Power (VDD) |
|--------------|-------------------|
| IGD1205W-12  | 12 VDC            |
| IGD1205W-15  | 15 VDC            |
|              |                   |

## **Pin Connections**

| Pin | Function               | Pin | Function               |
|-----|------------------------|-----|------------------------|
| 1   | Control Pin (ForTTRIP) | 8   | DC/DC Ouput (Comm)     |
| 2   | Fault Signal Output    | 9   | DC/DC Ouput (+)        |
| 3   | Soft Turn-Off Adj      | 13  | Drive Signal Input (-) |
| 4   | Fault Detection        | 14  | Drive Signal Input (+) |
| 5   | Internal Power Tube    | 15  | -VDD (- Power Supply)  |
| 6   | Drive Output           | 16  | +VDD (+ Power Supply)  |
| 7   | DC/DC Ouput (-)        |     |                        |

 All dimensions are typical in inches (mm) • Tolerance  $x.xx = \pm 0.01 \ (\pm 0.25)$ 



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